



RATING AND CHARACTERISTIC CURVES INVERSE

FAST SWITCHING DIODE

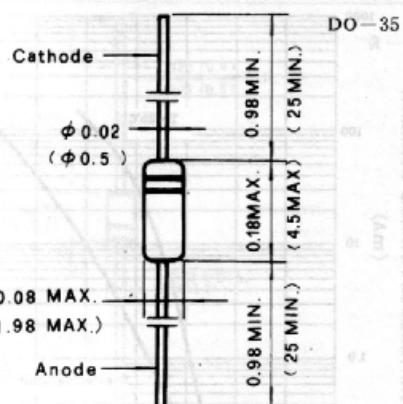
1N4148

FEATURES

- Extrem fast swithing.
- Low cost.

MECHANICAL DATA

- Case: Glass sealed envelope.
- Polarity: Color band denotes cathode end.
- Lead: Plated lead, solderable per MIL-STD-202E method 208C
- Mounting position: Any
- Weight: 0.005 ounce, 0.15 gram

VOLTAGE RANGE 75 Volts
CURRENT RATE 150 Milliamperes

Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load derate current by 20%.

	SYMBOLS	1N4148	UNITS
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100	Volts
Maximum DC Blocking Voltage	V_{DC}	75	Volts
Maximum Average Forward Rectified Current, 0.375" (9.5mm) Lead length at $T_A = 25^\circ\text{C}$	$I_{(AV)}$	150	mAmps
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{PSM}	500	mAmps
Maximum Instantaneous Forward Voltage Drop at 10 mA	V_F	1.0	Volts
Maximum DC Reverse Current at rated DC blocking voltage	I_R	5.0	μA
$T_A = 150^\circ\text{C}, V_R = 20\text{V}$		50	
Maximum Reverse Recovery Time (Note 1)	t_{rr}	4.0	nS
Typical Junction Capacitance (Note 2)	C_J	4.0	pF
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +200	°C

NOTES:

- Test condition: $I_F = 10\text{mA}$, $I_R = 1\text{mA}$, $V_R = 6\text{V}$, $R_L = 100\Omega$.
- Measured at 1.0MHz and applied reverse voltage of 4.0volts.

3. Thermal Resistance from Junction to Ambient at 375°C. Only measured at 1.0MHz and applied reverse voltage of 4.0volts.

RATINGS AND CHARACTERISTIC CURVES IN4148

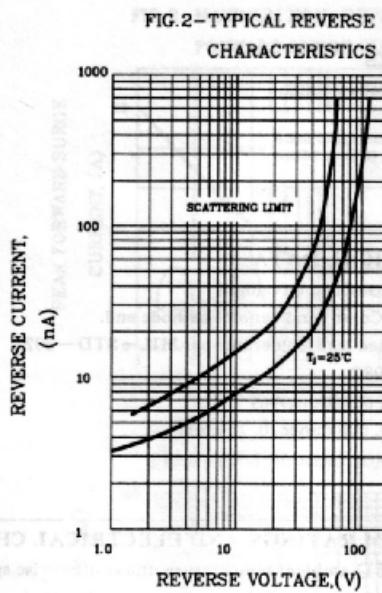
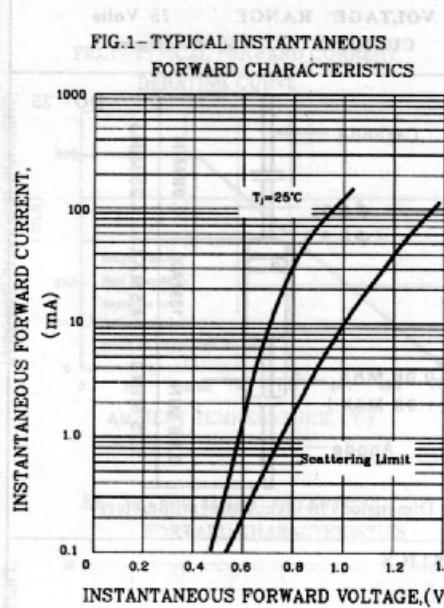
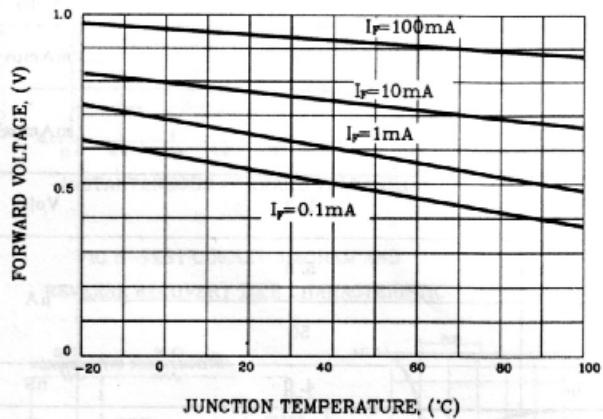


FIG.3-TYPICAL FORWARD VOLTAGE VS JUNCTION TEMPERATURE



NOTES:
 1. Test conditions: $I_F = 50 \text{ mA}$, $V_G = 2 \text{ V}$, $A_{FD} = 10^3$, $A_{RD} = 10^3$, $T_j = 25^\circ\text{C}$.
 2. Die Sheet Resistance: $10 \Omega/\square$.

NOTES:
 1. Test conditions: $I_F = 50 \text{ mA}$, $V_G = 2 \text{ V}$, $A_{FD} = 10^3$, $A_{RD} = 10^3$, $T_j = 25^\circ\text{C}$.
 2. Measured at 1 GHz using 10 mV ac voltage across $1 \text{ k}\Omega$.